

# 7MBR15XKA120-50

IGBT Modules

**Power Module(X series)**  
1200V / 15A / PIM

■ **Features**

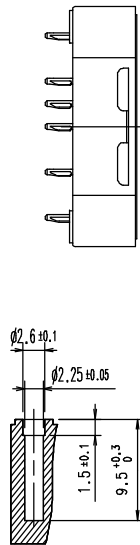
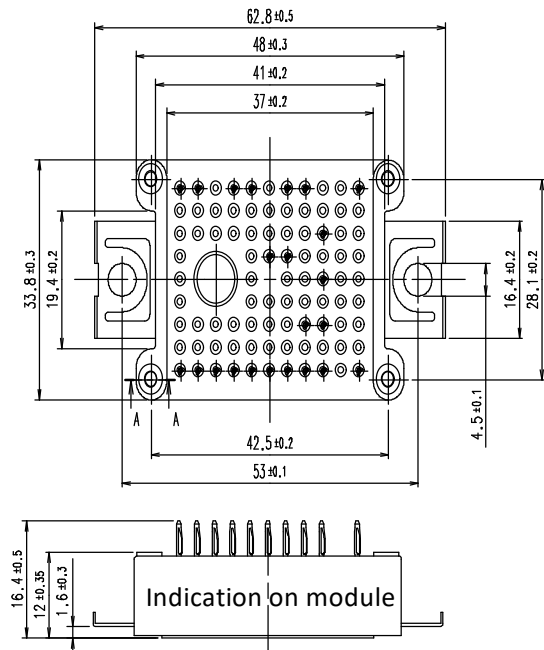
- Low  $V_{CE(sat)}$
- Compact Package
- P.C.Board Mount Module
- Converter Diode Bridge Dynamic Brake Circuit
- RoHS compliant Product

■ **Applications**

- Inverter for Motor Drive
- AC and DC Servo Drive Amplifier
- Uninterrupted Power Supply

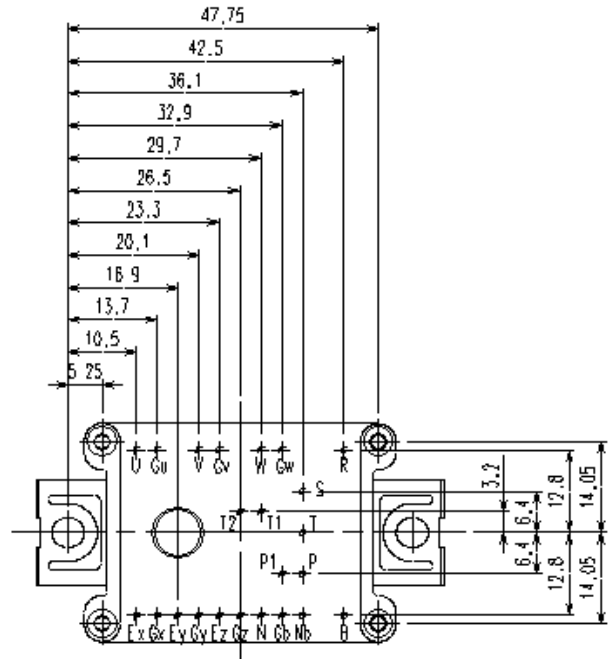
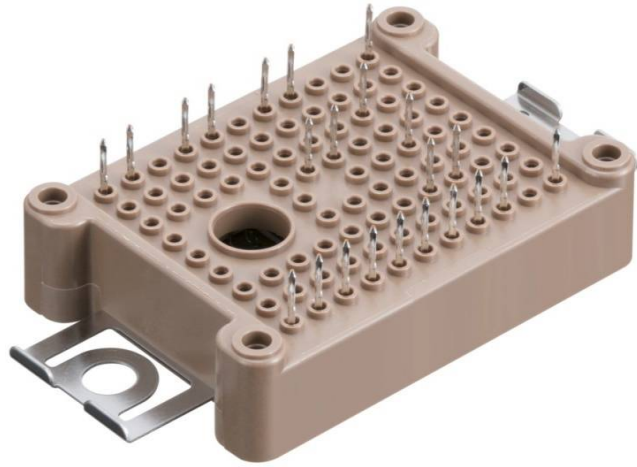
■ **Outline drawing ( Unit : mm )**

shows theoretical dimension.  
( ) shows reference dimension.



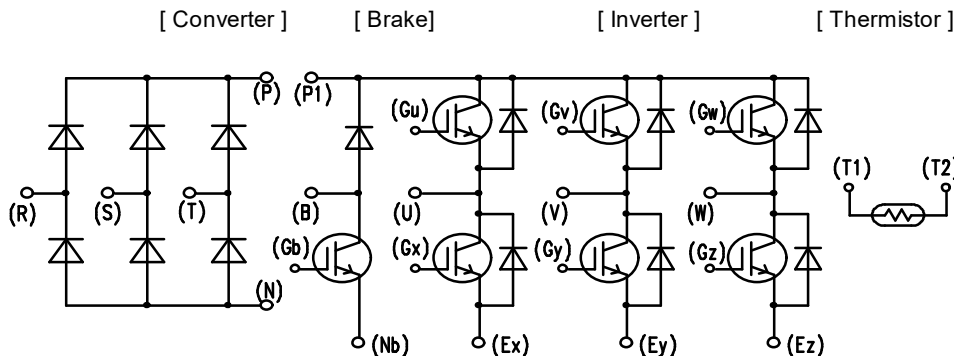
断面A-A (1.5:1)  
SECTION A-A  
Weight: 25 g (typ.)

■ **Typical appearance**



ALL DIMENSION IN THE LEFT FIGURE ARE REFERENCE  
PIN POSITION TO DESIGNED CENTER OF MODULE  $\oplus \phi 0.7$   
PIN-GRID SPACING 3.2mm

■ **Equivalent circuit**



# 7MBR15XKA120-50

**IGBT Modules**
**■ Maximum ratings ( at  $T_c = 25^\circ\text{C}$  unless otherwise specified )**

| Items   |  | Symbols    | Conditions                              |                            | Maximum ratings | Units                |
|---|--|------------|---|----------------------------|-----------------|----------------------|
| Inverter  | Collector-Emitter voltage, Gate-Emitter short-circuited                      | $V_{CES}$  |   |                            | 1200            | V                    |
|   | Gate-Emitter voltage, Collector-Emitter short-circuited                      | $V_{GES}$  |   |                            | $\pm 20$        | V                    |
|   | Collector current  | $I_C$      | Continuous                              | $T_c=100^\circ\text{C}$    | 15              | A                    |
|   | Repetitive peak collector current  | $I_{CRM}$  | 1ms                                     |                            | 30              |                      |
|   | Forward current  | $I_F$      | Continuous                              |                            | 15              |                      |
|   | Repetitive peak forward current  | $I_{FRM}$  | 1ms                                     |                            | 30              |                      |
|   | Total power dissipation  | $P_{tot}$  | 1 device                                |                            | 135             | W                    |
| Brake IGBT  | Collector-Emitter voltage, Gate-Emitter short-circuited                      | $V_{CES}$  |   |                            | 1200            | V                    |
|   | Gate-Emitter voltage, Collector-Emitter short-circuited                      | $V_{GES}$  |   |                            | $\pm 20$        | V                    |
|   | Collector current  | $I_C$      | Continuous                              | $T_c=100^\circ\text{C}$    | 15              | A                    |
|   | Repetitive peak collector current  | $I_{CRM}$  | 1ms                                     |                            | 30              |                      |
|   | Total power dissipation  | $P_{tot}$  | 1 device                                |                            | 135             | W                    |
| Brake FWD   | Forward current  | $I_F$      | Continuous                              |                            | 10              | A                    |
|   | Repetitive peak forward current  | $I_{FRM}$  | 1ms                                     |                            | 20              |                      |
|   | Repetitive peak reverse voltage  | $V_{RRM}$  |   |                            | 1200            | V                    |
| Converter   | Repetitive peak reverse voltage  | $V_{RRM}$  |   |                            | 1600            | V                    |
|   | Average output current   | $I_O$      | Three-phase full wave rectified current | $T_c=80^\circ\text{C}$     | 15              | A                    |
|   | Surge forward current (Non-Repetitive) (*1)                                  | $I_{FSM}$  | $t=10\text{ms}$ , Half sine wave form   | $T_{vj}=25^\circ\text{C}$  | 350             | A                    |
|   |  |            |   | $T_{vj}=150^\circ\text{C}$ | 300             |                      |
|   | $I^2t$ (Non-Repetitive) (*1)   | $I^2t$     |   | $T_{vj}=25^\circ\text{C}$  | 615             | $\text{A}^2\text{s}$ |
|   |  |            | $T_{vj}=150^\circ\text{C}$              | 450                        |                 |                      |
| Virtual Junction temperature  |  | $T_{vj}$   | Inverter, Brake                         |                            | 175             | $^\circ\text{C}$     |
|   |  |            | Converter                               |                            | 150             |                      |
| Operating Virtual junction temperature (under switching conditions) |  | $T_{vjop}$ | Inverter, Brake                         |                            | 175             |                      |
|   |  |            | Converter                               |                            | 150             |                      |
| Case temperature  |  | $T_c$      |   |                            | 125             |                      |
| Storage temperature   |  | $T_{stg}$  |   |                            | -40 ~ 125       |                      |
| Isolation voltage   | between terminals and copper base (*2)<br>between thermistor and others (*3) | $V_{isol}$ | A.C. : 1min.                            |                            | 2500            | Vrms                 |
| Screw torque  | Mounting torque of screws to heat sink                                       | $M_s$      | M4                                      |                            | 1.3~1.7         | N·m                  |

(\*1)  $T_{vj}$  : Temperature at test start.

(\*2) All terminals should be connected together during the test.

(\*3) Two thermistor terminals should be connected together, other terminals should be connected together and shorted to base plate during the test.

# 7MBR15XKA120-50

**IGBT Modules**
**■ Electrical characteristics ( at  $T_{vj} = 25^{\circ}\text{C}$  unless otherwise specified)**

| Items   | Symbols   | Conditions  | Characteristics              |      |      | Units         |               |
|---|---|---|------------------------------|------|------|---------------|---------------|
|   |   |   | min.                         | typ. | max. |               |               |
| Collector-Emitter cut-off current, Gate-Emitter short-circuited | $I_{CES}$   | $V_{GE} = 0\text{V}$<br>$V_{CE} = 1200\text{V}$   | -                            | -    | 50   | $\mu\text{A}$ |               |
| Gate leakage current, Collector-Emitter short-circuited         | $I_{GES}$   | $V_{CE} = 0\text{V}$ $V_{GE} = +20/-20\text{V}$   | -                            | -    | 100  | nA            |               |
| Gate-Emitter threshold voltage                                  | $V_{GE(th)}$  | $V_{CE} = 20\text{V}$<br>$I_C = 15\text{mA}$  | 6.0                          | 6.5  | 7.0  | V             |               |
| Collector-Emitter saturation voltage                            | $V_{CE(sat)}$ (terminal)  | $V_{GE} = 15\text{V}$<br>$I_C = 15\text{A}$   | $T_{vj}=25^{\circ}\text{C}$  | -    | 1.65 | 2.10          | V             |
|   |   |   | $T_{vj}=25^{\circ}\text{C}$  | -    | 1.50 | 1.95          |               |
|   | $V_{CE(sat)}$ (chip)  | $T_{vj}=125^{\circ}\text{C}$  | -                            | 1.85 | -    |               |               |
|   |   | $T_{vj}=150^{\circ}\text{C}$  | -                            | 1.95 | -    |               |               |
| Internal gate resistance  | $r_g$   | -   | -                            | 0    | -    | $\Omega$      |               |
|   |   |   | -                            | 0    | -    | $\Omega$      |               |
| Capacitance   | $C_{ies}$   | $V_{CE} = 10\text{V}, V_{GE} = 0\text{V}, f = 1\text{MHz}$  | -                            | 1.6  | -    | nF            |               |
|   | $C_{oes}$   |   | -                            | 0.05 | -    |               |               |
|   | $C_{res}$   |   | -                            | 0.01 | -    |               |               |
| Gate charge   | $Q_G$   | $V_{CC} = 600\text{V}$ $V_{GE} = -15 \rightarrow +15\text{V}$<br>$I_C = 15\text{A}$                                       | -                            | 100  | -    | nC            |               |
| Forward voltage   | $V_F$ (terminal)  | $I_F = 15\text{A}$  | $T_{vj}=25^{\circ}\text{C}$  | -    | 2.35 | 2.80          | V             |
|   | $V_F$ (chip)  |   | $T_{vj}=25^{\circ}\text{C}$  | -    | 2.20 | 2.65          |               |
|   |   |   | $T_{vj}=125^{\circ}\text{C}$ | -    | 2.30 | -             |               |
|   |   |   | $T_{vj}=150^{\circ}\text{C}$ | -    | 2.30 | -             |               |
|   |   |   | $T_{vj}=175^{\circ}\text{C}$ | -    | 2.25 | -             |               |
| Switching time (*1)   | $t_{d(on)}$   | $V_{CC} = 600\text{V}$<br>$I_C, I_F = 15\text{A}$ $L_s = 30\text{nH}$<br>$V_{GE} = +15/-15\text{V}$<br>$R_G = 39\ \Omega$ | $T_{vj}=25^{\circ}\text{C}$  | -    | 0.06 | -             | $\mu\text{s}$ |
|   |   |   | $T_{vj}=125^{\circ}\text{C}$ | -    | 0.06 | -             |               |
|   |   |   | $T_{vj}=150^{\circ}\text{C}$ | -    | 0.06 | -             |               |
|   |   |   | $T_{vj}=175^{\circ}\text{C}$ | -    | 0.06 | -             |               |
|   | $t_r$   | $V_{CC} = 600\text{V}$<br>$I_C, I_F = 15\text{A}$ $L_s = 30\text{nH}$<br>$V_{GE} = +15/-15\text{V}$<br>$R_G = 39\ \Omega$ | $T_{vj}=25^{\circ}\text{C}$  | -    | 0.03 | -             |               |
|   |   |   | $T_{vj}=125^{\circ}\text{C}$ | -    | 0.03 | -             |               |
|   |   |   | $T_{vj}=150^{\circ}\text{C}$ | -    | 0.03 | -             |               |
|   |   |   | $T_{vj}=175^{\circ}\text{C}$ | -    | 0.03 | -             |               |
|   | $t_{d(off)}$  | $V_{CC} = 600\text{V}$<br>$I_C, I_F = 15\text{A}$ $L_s = 30\text{nH}$<br>$V_{GE} = +15/-15\text{V}$<br>$R_G = 39\ \Omega$ | $T_{vj}=25^{\circ}\text{C}$  | -    | 0.20 | -             |               |
|   |   |   | $T_{vj}=125^{\circ}\text{C}$ | -    | 0.23 | -             |               |
|   |   |   | $T_{vj}=150^{\circ}\text{C}$ | -    | 0.24 | -             |               |
|   |   |   | $T_{vj}=175^{\circ}\text{C}$ | -    | 0.25 | -             |               |
| $t_f$   | $V_{CC} = 600\text{V}$<br>$I_C, I_F = 15\text{A}$ $L_s = 30\text{nH}$<br>$V_{GE} = +15/-15\text{V}$<br>$R_G = 39\ \Omega$ | $T_{vj}=25^{\circ}\text{C}$   | -                            | 0.12 | -    |               |               |
|   |   | $T_{vj}=125^{\circ}\text{C}$  | -                            | 0.18 | -    |               |               |
|   |   | $T_{vj}=150^{\circ}\text{C}$  | -                            | 0.19 | -    |               |               |
|   |   | $T_{vj}=175^{\circ}\text{C}$  | -                            | 0.20 | -    |               |               |
| Reverse recovery time   | $t_{rr}$  | $V_{CC} = 600\text{V}$<br>$I_C, I_F = 15\text{A}$ $L_s = 30\text{nH}$<br>$V_{GE} = +15/-15\text{V}$<br>$R_G = 39\ \Omega$ | $T_{vj}=25^{\circ}\text{C}$  | -    | 0.07 | -             |               |
|   |   |   | $T_{vj}=125^{\circ}\text{C}$ | -    | 0.12 | -             |               |
|   |   |   | $T_{vj}=150^{\circ}\text{C}$ | -    | 0.15 | -             |               |
|   |   |   | $T_{vj}=175^{\circ}\text{C}$ | -    | 0.18 | -             |               |

(\*1) Turn on time ( $t_{on}$ ) =  $t_{d(on)} + t_r$ , Turn off time ( $t_{off}$ ) =  $t_{d(off)} + t_f$

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**IGBT Modules**

| Items   | Symbols                  | Conditions  |                        | Characteristics |      |          | Units    |
|---|--------------------------|---|------------------------|-----------------|------|----------|----------|
|   |                          |   |                        | min.            | typ. | max.     |          |
| Inverter<br>Switching loss<br>(per pulse)                       | $E_{on}$                 | $V_{CC} = 600V$<br>$I_C, I_F = 15A \quad L_s = 30nH$<br>$V_{GE} = +15/-15V$<br>$R_G = 39\Omega$ | $T_{vj} = 25^\circ C$  | -               | 1.11 | -        | mJ       |
|   |                          |   | $T_{vj} = 125^\circ C$ | -               | 1.36 | -        |          |
|   |                          |   | $T_{vj} = 150^\circ C$ | -               | 1.48 | -        |          |
|   |                          |   | $T_{vj} = 175^\circ C$ | -               | 1.57 | -        |          |
|   | $E_{off}$                | $V_{CC} = 600V$<br>$I_C, I_F = 15A \quad L_s = 30nH$<br>$V_{GE} = +15/-15V$<br>$R_G = 39\Omega$ | $T_{vj} = 25^\circ C$  | -               | 1.06 | -        |          |
|   |                          |   | $T_{vj} = 125^\circ C$ | -               | 1.35 | -        |          |
|   |                          |   | $T_{vj} = 150^\circ C$ | -               | 1.43 | -        |          |
|   |                          |   | $T_{vj} = 175^\circ C$ | -               | 1.52 | -        |          |
|   | $E_{rr}$                 | $V_{CC} = 600V$<br>$I_C, I_F = 15A \quad L_s = 30nH$<br>$V_{GE} = +15/-15V$<br>$R_G = 39\Omega$ | $T_{vj} = 25^\circ C$  | -               | 0.63 | -        |          |
|   |                          |   | $T_{vj} = 125^\circ C$ | -               | 0.91 | -        |          |
|   |                          |   | $T_{vj} = 150^\circ C$ | -               | 1.09 | -        |          |
|   |                          |   | $T_{vj} = 175^\circ C$ | -               | 1.17 | -        |          |
| Collector-Emitter cut-off current, Gate-Emitter short-circuited | $I_{CES}$                | $V_{GE} = 0V$<br>$V_{CE} = 1200V$   | -                      | -               | 50   | $\mu A$  |          |
| Gate leakage current, Collector-Emitter short-circuited         | $I_{GES}$                | $V_{CE} = 0V, \quad V_{GE} = +20/-20V$  | -                      | -               | 100  | nA       |          |
| Collector-Emitter saturation voltage                            | $V_{CE(sat)}$ (terminal) | $V_{GE} = 15V$<br>$I_C = 15A$   | $T_{vj} = 25^\circ C$  | -               | 1.65 | 2.10     | V        |
|   |                          |   | $T_{vj} = 25^\circ C$  | -               | 1.50 | 1.95     |          |
|   | $V_{CE(sat)}$ (chip)     |   | $T_{vj} = 125^\circ C$ | -               | 1.85 | -        |          |
|   |                          |   | $T_{vj} = 150^\circ C$ | -               | 1.95 | -        |          |
| Internal gate resistance  | $r_g$                    | -   | $T_{vj} = 25^\circ C$  | -               | 0    | -        | $\Omega$ |
|   |                          |   | $T_{vj} = 125^\circ C$ | -               | 0    | -        |          |
|   |                          |   | $T_{vj} = 150^\circ C$ | -               | 0    | -        |          |
|   |                          |   | $T_{vj} = 175^\circ C$ | -               | 0    | -        |          |
| Brake<br>Switching time (*1)                                    | $t_{d(on)}$              | $V_{CC} = 600V$<br>$I_C = 15A \quad L_s = 30nH$<br>$V_{GE} = +15/-15V$<br>$R_G = 39\Omega$      | $T_{vj} = 25^\circ C$  | -               | 0.06 | -        | $\mu s$  |
|   |                          |   | $T_{vj} = 125^\circ C$ | -               | 0.06 | -        |          |
|   |                          |   | $T_{vj} = 150^\circ C$ | -               | 0.06 | -        |          |
|   |                          |   | $T_{vj} = 175^\circ C$ | -               | 0.06 | -        |          |
|   | $t_r$                    | $V_{CC} = 600V$<br>$I_C = 15A \quad L_s = 30nH$<br>$V_{GE} = +15/-15V$<br>$R_G = 39\Omega$      | $T_{vj} = 25^\circ C$  | -               | 0.03 | -        |          |
|   |                          |   | $T_{vj} = 125^\circ C$ | -               | 0.03 | -        |          |
|   |                          |   | $T_{vj} = 150^\circ C$ | -               | 0.03 | -        |          |
|   |                          |   | $T_{vj} = 175^\circ C$ | -               | 0.03 | -        |          |
|   | $t_{d(off)}$             | $V_{CC} = 600V$<br>$I_C = 15A \quad L_s = 30nH$<br>$V_{GE} = +15/-15V$<br>$R_G = 39\Omega$      | $T_{vj} = 25^\circ C$  | -               | 0.20 | -        |          |
|   |                          |   | $T_{vj} = 125^\circ C$ | -               | 0.23 | -        |          |
|   |                          |   | $T_{vj} = 150^\circ C$ | -               | 0.24 | -        |          |
|   |                          |   | $T_{vj} = 175^\circ C$ | -               | 0.25 | -        |          |
|   | $t_f$                    | $V_{CC} = 600V$<br>$I_C = 15A \quad L_s = 30nH$<br>$V_{GE} = +15/-15V$<br>$R_G = 39\Omega$      | $T_{vj} = 25^\circ C$  | -               | 0.12 | -        |          |
|   |                          |   | $T_{vj} = 125^\circ C$ | -               | 0.18 | -        |          |
|   |                          |   | $T_{vj} = 150^\circ C$ | -               | 0.19 | -        |          |
|   |                          |   | $T_{vj} = 175^\circ C$ | -               | 0.20 | -        |          |
| Reverse current   | $I_{RRM}$                | $V_R = 1200V$   | -                      | -               | 50   | $\mu A$  |          |
| Forward voltage   | $V_F$ (terminal)         | $I_F = 10A$   | $T_j = 25^\circ C$     | -               | 2.05 | 2.50     | V        |
|   |                          |   | $T_{vj} = 25^\circ C$  | -               | 1.90 | 2.35     |          |
|   | $V_F$ (chip)             |   | $T_{vj} = 125^\circ C$ | -               | 1.95 | -        |          |
|   |                          |   | $T_{vj} = 150^\circ C$ | -               | 1.90 | -        |          |
| Thermistor Converter  | $I_{RRM}$                | $V_R = 1600V$   | $T_{vj} = 175^\circ C$ | -               | 1.85 | -        |          |
|   |                          |   | $T_{vj} = 150^\circ C$ | -               | 1.90 | -        |          |
|   |                          |   | $T_{vj} = 125^\circ C$ | -               | 1.95 | -        |          |
|   |                          |   | $T_{vj} = 25^\circ C$  | -               | 2.05 | 2.50     |          |
| Continuous (direct) forward voltage                             | $V_F$                    | $I_F = 15A$   | terminal               | -               | 1.15 | 1.60     | V        |
|   |                          |   | chip                   | -               | 1.00 | 1.45     |          |
| Resistance  | $R$                      | $T = 25^\circ C$  | -                      | 5000            | -    | $\Omega$ |          |
|   |                          | $T = 100^\circ C$   | 465                    | 495             | 520  |          |          |
| B value   | $B$                      | $T = 25/50^\circ C$   | 3305                   | 3375            | 3450 | K        |          |

 (\*1) Turn on time ( $t_{on}$ ) =  $t_{d(on)} + t_r$ , Turn off time ( $t_{off}$ ) =  $t_{d(off)} + t_f$

# 7MBR15XKA120-50

**NOTICE:**

The external gate resistance ( $R_G$ ) shown above is one of our recommended value for the purpose of minimum switching loss. However the optimum  $R_G$  depends on circuit configuration and/or environment. We recommend that the  $R_G$  has to be carefully chosen based on consideration if IGBT module matches design criteria, for example, switching loss, EMC/EMI, spike voltage, surge current and no unexpected oscillation and so on.

**■ Thermal resistance characteristics**

| Items  | Symbols       | Conditions      | Characteristics |      |      | Units |
|--|---------------|-----------------|-----------------|------|------|-------|
|  |               |                 | min.            | typ. | max. |       |
| Thermal resistance junction to case (1 device)         | $R_{th(j-c)}$ | Inverter IGBT   | -               | -    | 1.09 | °C/W  |
|  |               | Inverter FWD    | -               | -    | 1.75 |       |
|  |               | Brake IGBT      | -               | -    | 1.09 |       |
|  |               | Brake FWD       | -               | -    | 1.75 |       |
|  |               | Converter Diode | -               | -    | 0.97 |       |
| Thermal resistance case to heat sink(*1)<br>(1 device) | $R_{th(c-s)}$ | Inverter IGBT   | -               | 0.76 | -    |       |
|  |               | Inverter FWD    | -               | 0.92 | -    |       |
|  |               | Brake IGBT      | -               | 0.79 | -    |       |
|  |               | Brake FWD       | -               | 0.75 | -    |       |
|  |               | Converter Diode | -               | 0.78 | -    |       |

(\*1) This is the value which is defined mounting on the additional cooling fin with 1 W/(m·K) thermal grease.

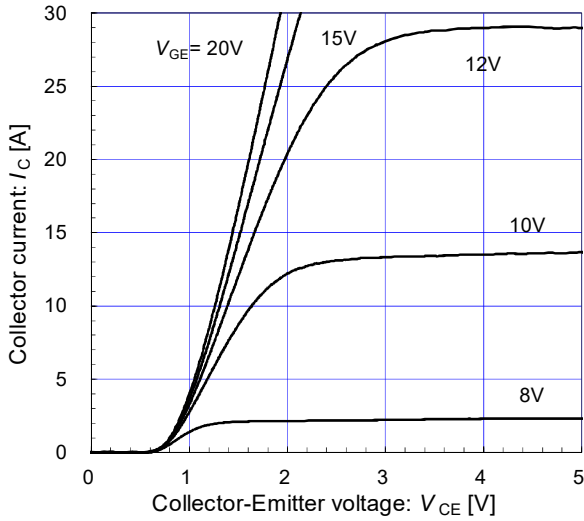
# 7MBR15XKA120-50

IGBT Modules

[ Inverter ]

Collector current vs. Collector-Emitter voltage (typ.)

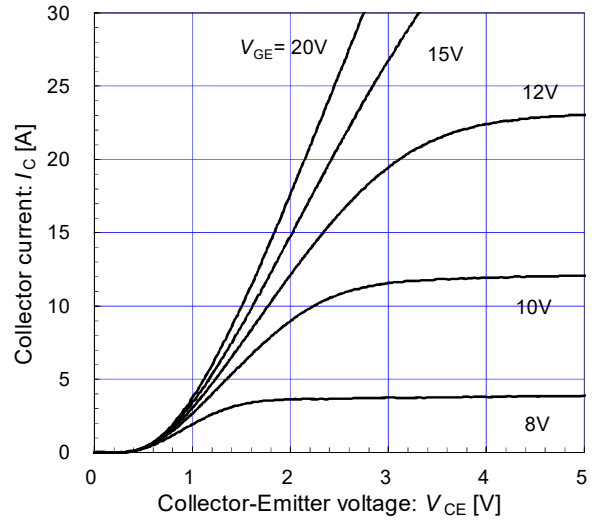
$T_{vj} = 25^\circ\text{C} / \text{chip}$



[ Inverter ]

Collector current vs. Collector-Emitter voltage (typ.)

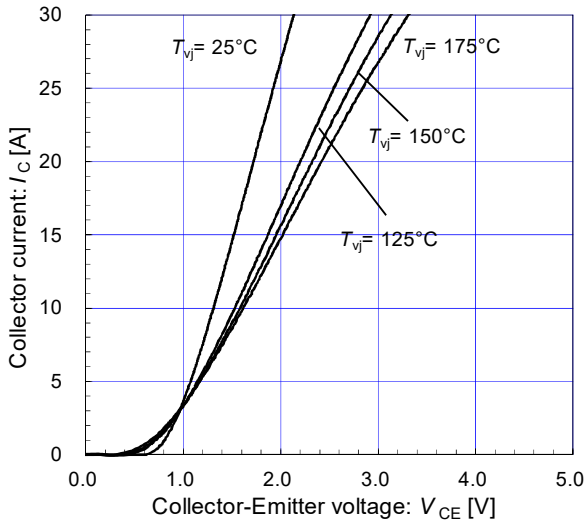
$T_{vj} = 175^\circ\text{C} / \text{chip}$



[ Inverter ]

Collector current vs. Collector-Emitter voltage (typ.)

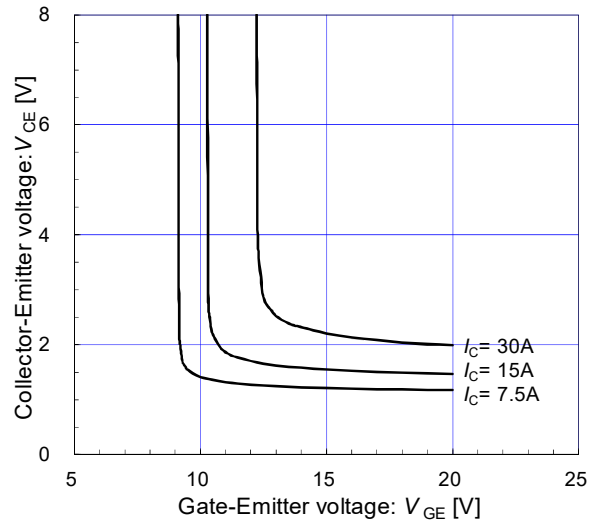
$V_{GE} = 15\text{V} / \text{chip}$



[ Inverter ]

Collector-Emitter voltage vs. Gate-Emitter voltage (typ.)

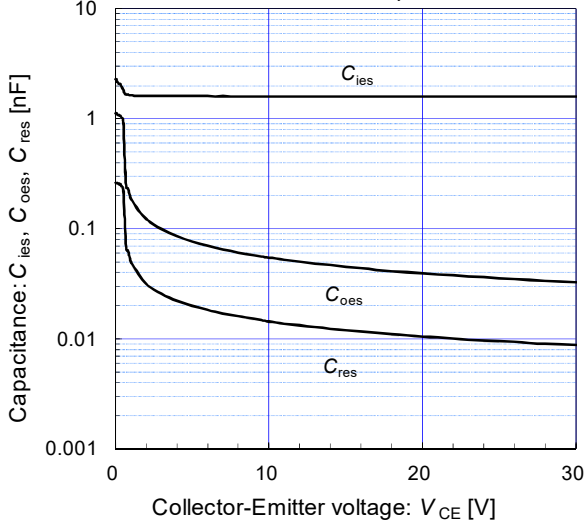
$T_{vj} = 25^\circ\text{C} / \text{chip}$



[ Inverter ]

Capacitance vs. Collector-Emitter voltage (typ.)

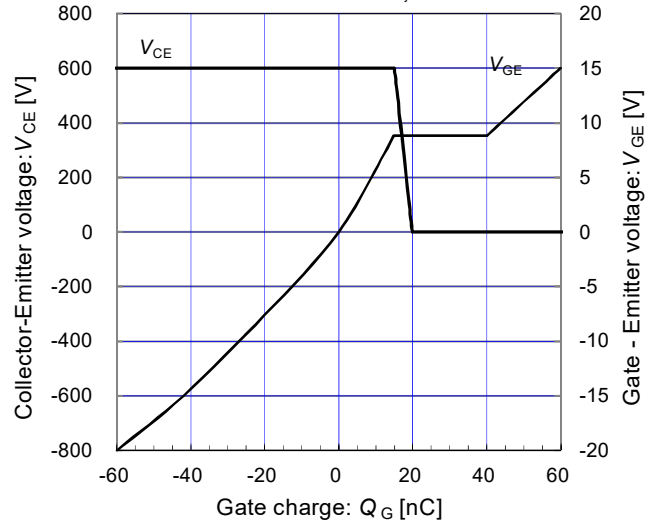
$V_{GE} = 0\text{V}, f = 1\text{MHz}, T_{vj} = 25^\circ\text{C}$



[ Inverter ]

Dynamic gate charge (typ.)

$V_{CC} = 600\text{V}, I_c = 15\text{A}, T_{vj} = 25^\circ\text{C}$

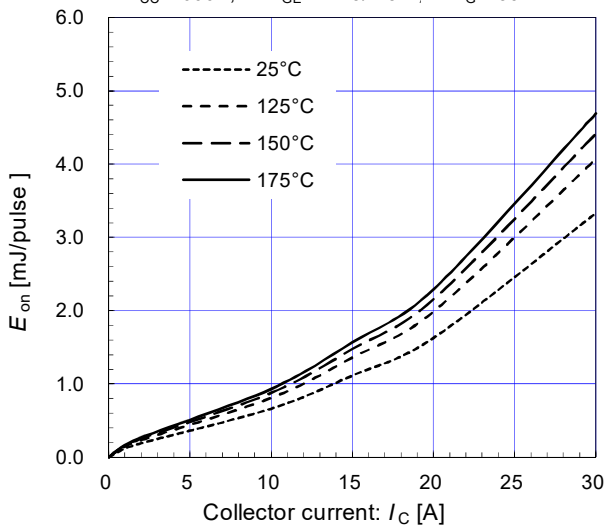


# 7MBR15XKA120-50

[ Inverter ]

$E_{on}$  vs. Collector current (typ.)

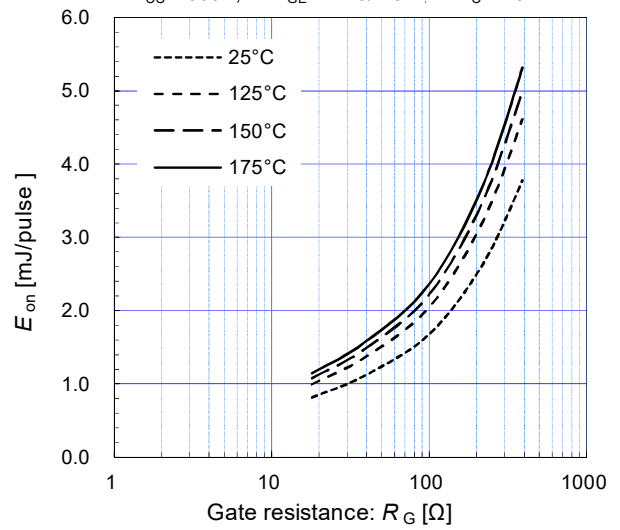
$V_{CC}=600V, V_{GE}=+15/-15V, R_G=39\Omega$



[ Inverter ]

$E_{on}$  vs. Gate resistance (typ.)

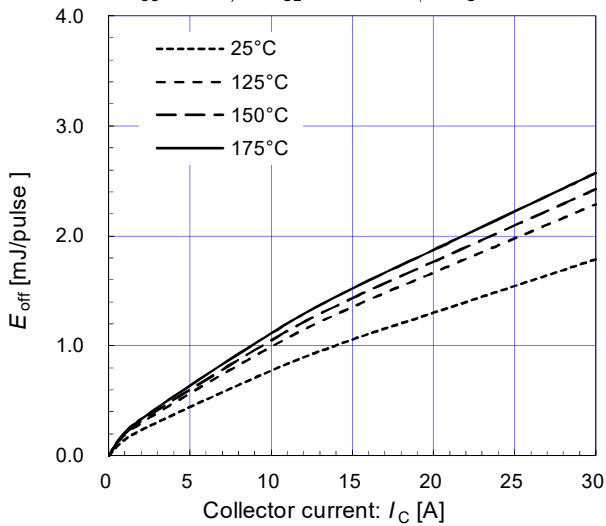
$V_{CC}=600V, V_{GE}=+15/-15V, I_C=15A$



[ Inverter ]

$E_{off}$  vs. Collector current (typ.)

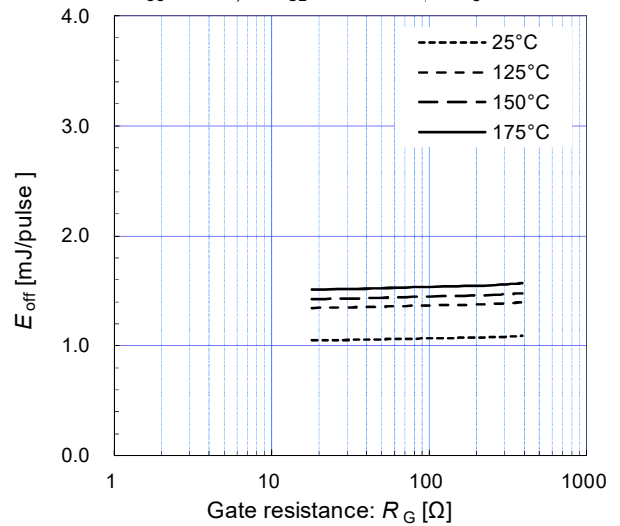
$V_{CC}=600V, V_{GE}=+15/-15V, R_G=39\Omega$



[ Inverter ]

$E_{off}$  vs. Gate resistance (typ.)

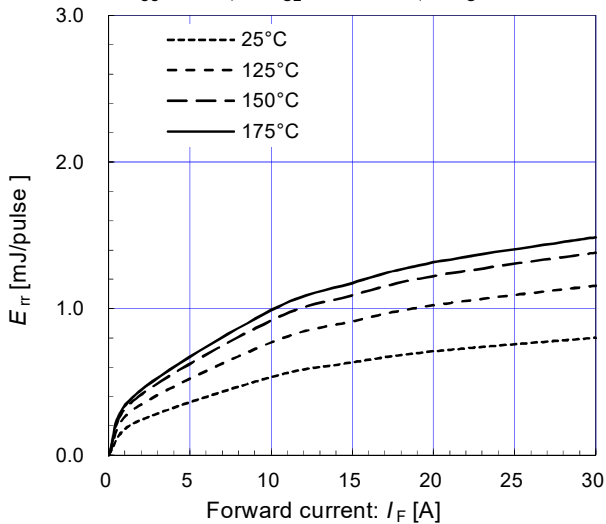
$V_{CC}=600V, V_{GE}=+15/-15V, I_C=15A$



[ Inverter ]

$E_{rr}$  vs. Forward current (typ.)

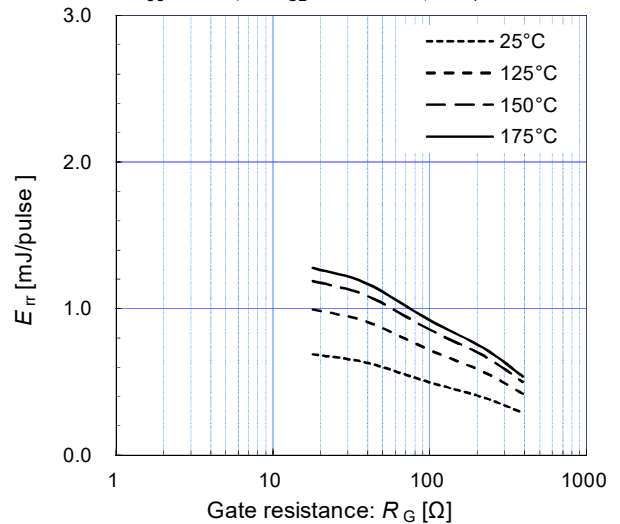
$V_{CC}=600V, V_{GE}=+15/-15V, R_G=39\Omega$



[ Inverter ]

$E_{rr}$  vs. Gate resistance (typ.)

$V_{CC}=600V, V_{GE}=+15/-15V, I_F=15A$

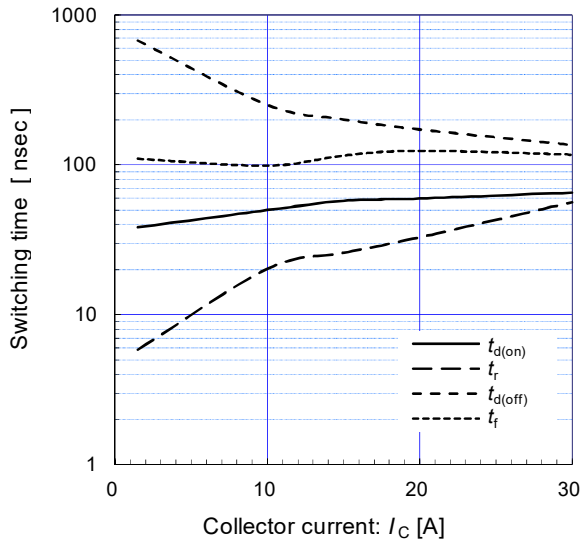


# 7MBR15XKA120-50

[ Inverter ]

Switching time vs. Collector current (typ.)

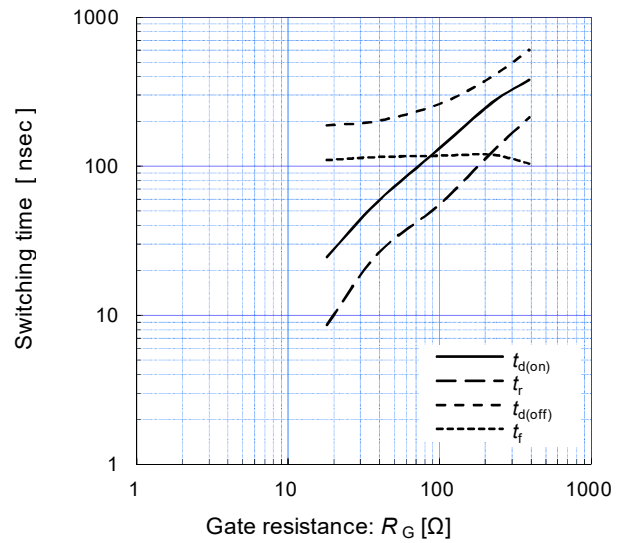
$V_{CC}=600V, R_G=39\Omega, V_{GE}=+15/-15V, T_{vj}=25^\circ C$



[ Inverter ]

Switching time vs. Gate resistance (typ.)

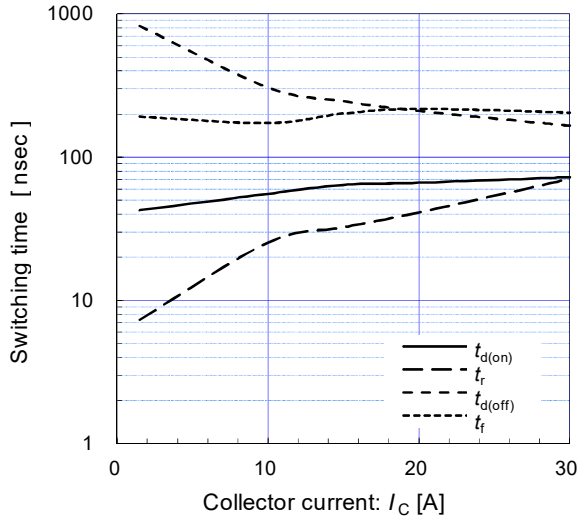
$V_{CC}=600V, I_C=15A, V_{GE}=+15/-15V, T_{vj}=25^\circ C$



[ Inverter ]

Switching time vs. Collector current (typ.)

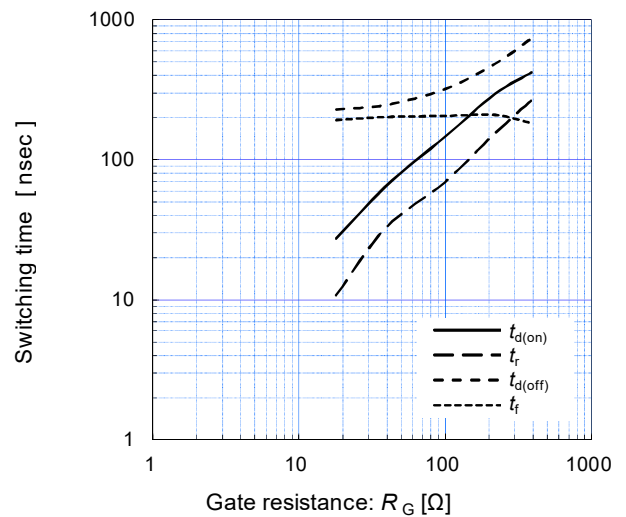
$V_{CC}=600V, R_G=39\Omega, V_{GE}=+15/-15V, T_{vj}=175^\circ C$



[ Inverter ]

Switching time vs. Gate resistance (typ.)

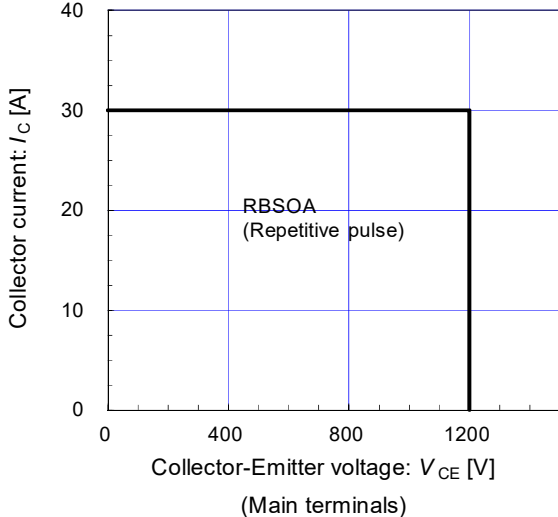
$V_{CC}=600V, I_C=15A, V_{GE}=+15/-15V, T_{vj}=175^\circ C$



[ Inverter ]

Reverse bias safe operating area (max.)

$V_{GE}=+15/-15V, R_G \geq 39\Omega, T_{vj}=175^\circ C$

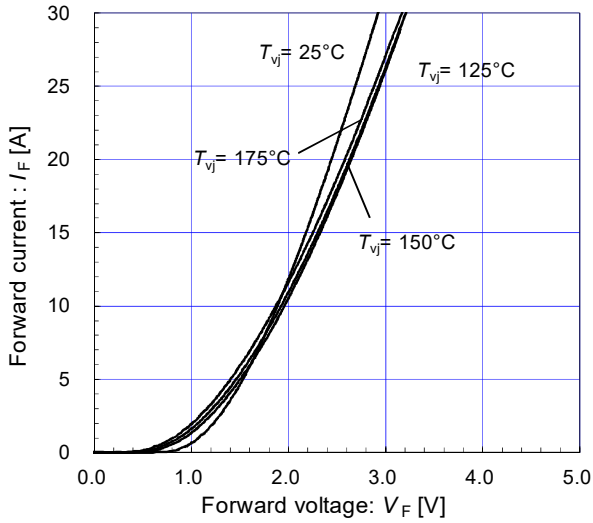


# 7MBR15XKA120-50

IGBT Modules

[ Inverter ]

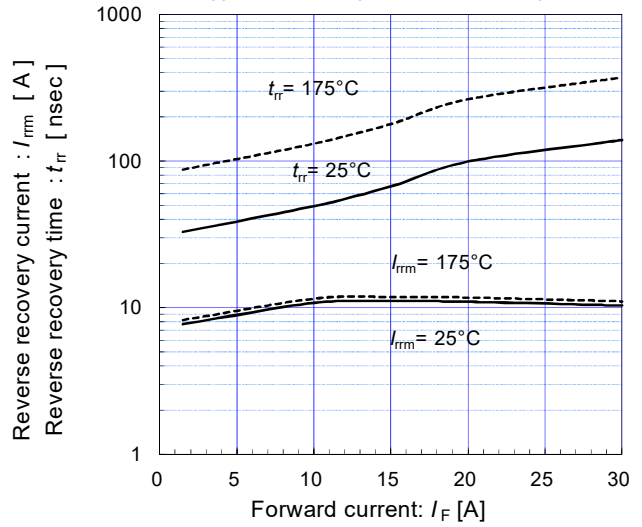
Forward current vs. Forward voltage (typ.)  
chip



[ Inverter ]

Reverse recovery characteristics (typ.)

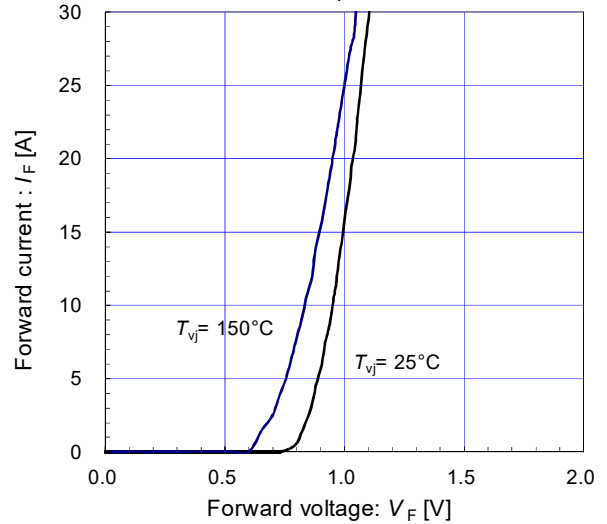
$V_{CC} = 600V, V_{GE} = +15/-15V, R_G = 39\Omega$



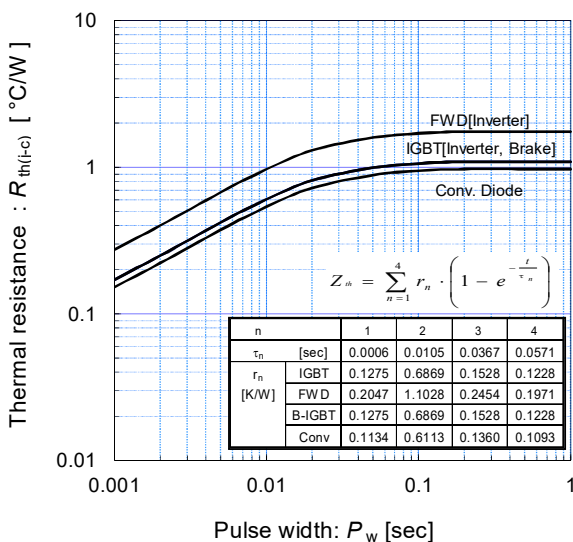
[ Converter ]

Forward current vs. Forward voltage (typ.)

chip

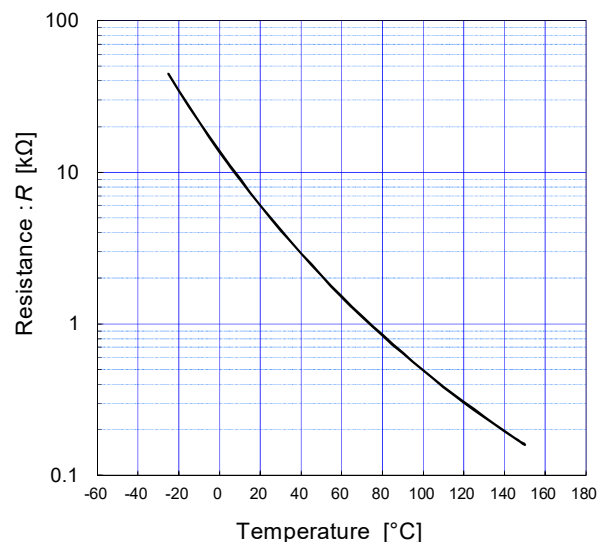


Transient thermal resistance (max.)



[ Thermistor ]

Temperature characteristic (typ.)

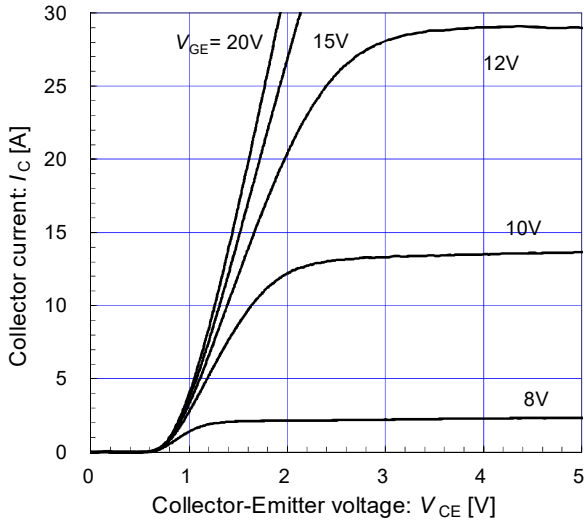


# 7MBR15XKA120-50

[ Brake ]

Collector current vs. Collector-Emmitter voltage (typ.)

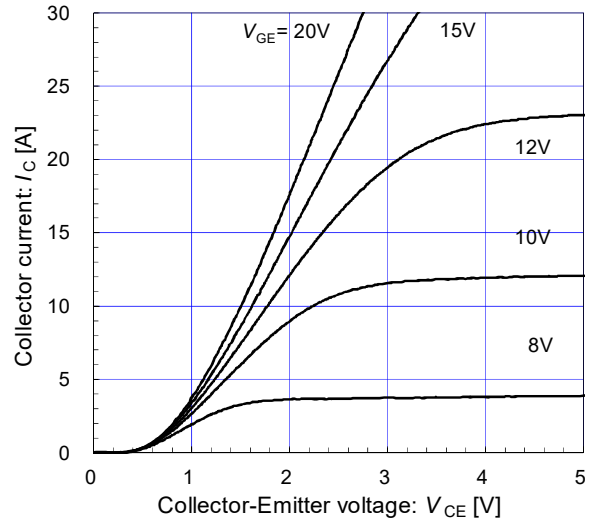
$T_{vj} = 25^\circ\text{C} / \text{chip}$



[ Brake ]

Collector current vs. Collector-Emmitter voltage (typ.)

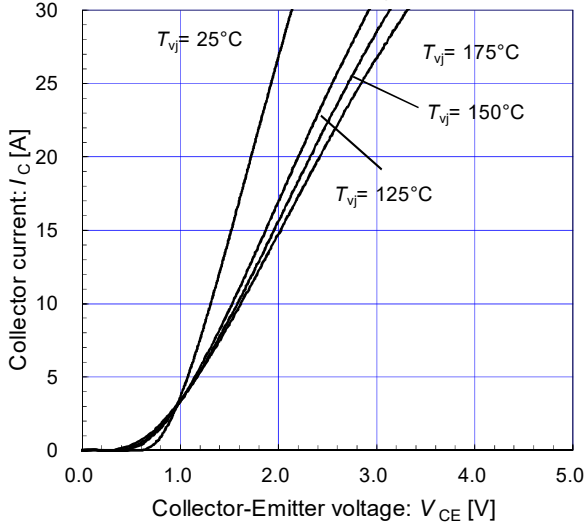
$T_{vj} = 175^\circ\text{C} / \text{chip}$



[ Brake ]

Collector current vs. Collector-Emmitter voltage (typ.)

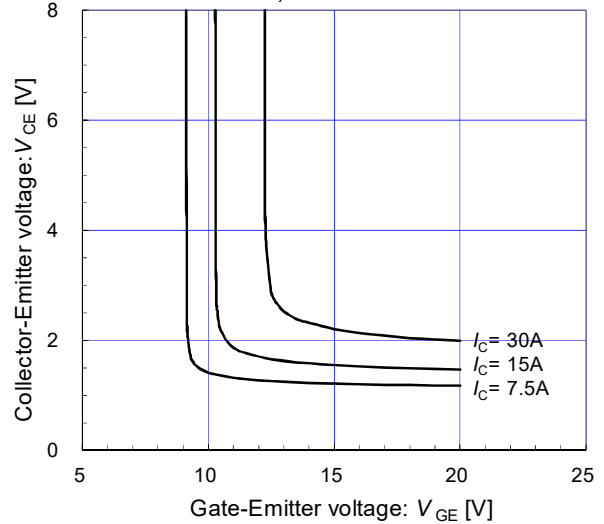
$V_{GE} = 15\text{V} / \text{chip}$



[ Brake ]

Collector-Emmitter voltage vs. Gate-Emmitter voltage (typ.)

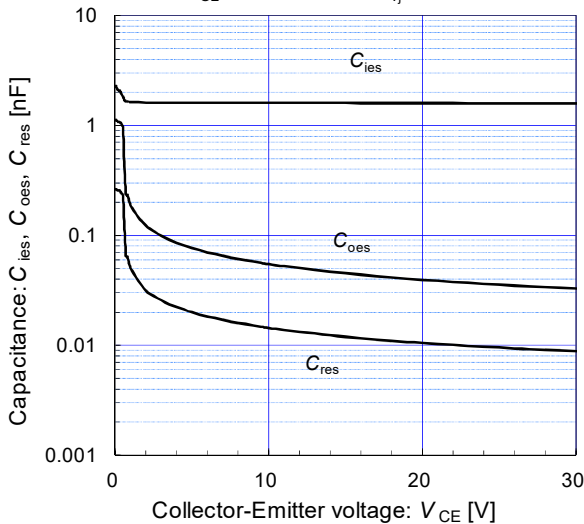
$T_{vj} = 25^\circ\text{C} / \text{chip}$



[ Brake ]

Capacitance vs. Collector-Emmitter voltage (typ.)

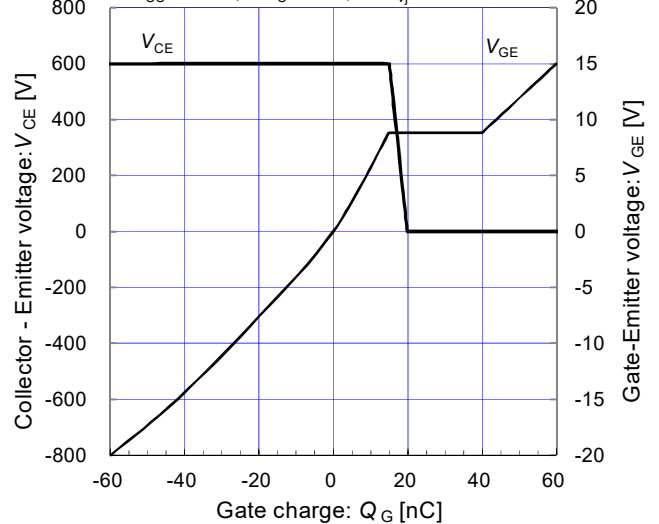
$V_{GE} = 0\text{V}, f = 1\text{MHz}, T_{vj} = 25^\circ\text{C}$



[ Brake ]

Dynamic gate charge (typ.)

$V_{CC} = 600\text{V}, I_C = 15\text{A}, T_{vj} = 25^\circ\text{C}$



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## IGBT Modules

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